- EPIC™ (Enhanced-Performance Implanted CMOS) Process
- Operating Range 2-V to 5.5-V V_{CC}
- Packaged in Plastic Small-Outline Transistor Package

description

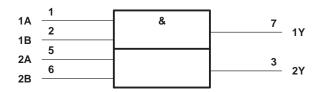
The SN74AHC2G08 is a dual 2-input positive-AND gate. The device performs the Boolean function $Y = A \bullet B$ or $Y = \overline{A} + \overline{B}$ in positive logic.

The SN74AHC2G08 is characterized for operation from -40°C to 85°C.

FUNCTION TABLE (each gate)

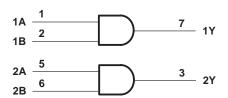
INPU	JTS	OUTPUT
Α	В	Υ
Н	Н	Н
L	X	L
X	L	L

logic symbol†



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)





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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage range, V _{CC}	0.5 V to 7 V
Input voltage range, V _I (see Note 1)	0.5 V to 7 V
Output voltage range, V _O (see Note 1)	$-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Input clamp current, I _{IK} (V _I < 0)	
Output clamp current, I _{OK} (V _O < 0 or V _O > V _{CC})	±20 mA
Continuous output current, I_O ($V_O = 0$ to V_{CC})	±25 mA
Continuous current through V _{CC} or GND	±50 mA
Package thermal impedance, θ _{JA} (see Note 2)	
Storage temperature range, T _{stq}	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions (see Note 3)

			MIN	MAX	UNIT	
Vcc	Supply voltage		2	5.5	V	
		V _{CC} = 2 V	1.5			
ViH	V _{IH} High-level input voltage	V _{CC} = 3 V	2.1		V	
		V _{CC} = 5.5 V	3.85			
		V _{CC} = 2 V		0.5		
VIL	Low-level input voltage	V _{CC} = 3 V		0.9	V	
		V _{CC} = 5.5 V		1.65		
٧ _I	Input voltage		0	5.5	V	
٧o	Output voltage		0	VCC	V	
		V _{CC} = 2 V		-50	μΑ	
IOH	High-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		-4	mA	
		$V_{CC} = 5 V \pm 0.5 V$		-8	IIIA	
		V _{CC} = 2 V		50	μΑ	
loL	Low-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		4	mA	
		$V_{CC} = 5 V \pm 0.5 V$		8	IIIA	
A4/A>	Input transition rise or fall rate	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		100	ns/V	
Δt/Δv	V _{CC} = 5 V \pm 0.5 V			20	115/ V	
TA	Operating free-air temperature		-40	85	°C	

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

^{2.} The package thermal impedance is calculated in accordance with JESD 51.

PRODUCT PREVIEW

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	vcc	T _A = 25°C			MIN	MAV	UNIT	
			MIN	TYP	MAX	IVIIIV	MAX	UNII	
			1.9	2		1.9			
		I _{OH} = -50 μA	3 V	2.9	3		2.9		
V _{OH}				4.4	4.5		4.4		V
		I _{OH} = -4 mA		2.58			2.48		
	$I_{OH} = -8 \text{ mA}$		4.5 V	3.94			3.8		
		Ι _{ΟL} = 50 μΑ				0.1		0.1	V
						0.1		0.1	
VOL						0.1		0.1	
I –		I _{OL} = 4 mA				0.36		0.44	
		I _{OL} = 8 mA				0.36		0.44	
II .	A or B inputs	$V_I = V_{CC}$ or GND	5.5 V			±0.1		±1	μΑ
Icc	·	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			1		10	μΑ
Ci		V _I = V _{CC} or GND	5 V						pF

switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	TO (OUTPUT)	OUTPUT CAPACITANCE	T _A = 25°C	MIN MAX	UNIT		
	(INPUT)			MIN TYP MAX	IVIIN IVIAX	ONIT		
t _{PLH}	A or B	Y	Y	Y C _L = 15 pF	C _L = 15 pF			ns
tPHL	AOIB					OL = 13 bi		
t _{PLH}	A or B	V	C: - 50 pF					
tPHL	AUID	ī	C _L = 50 pF			ns		

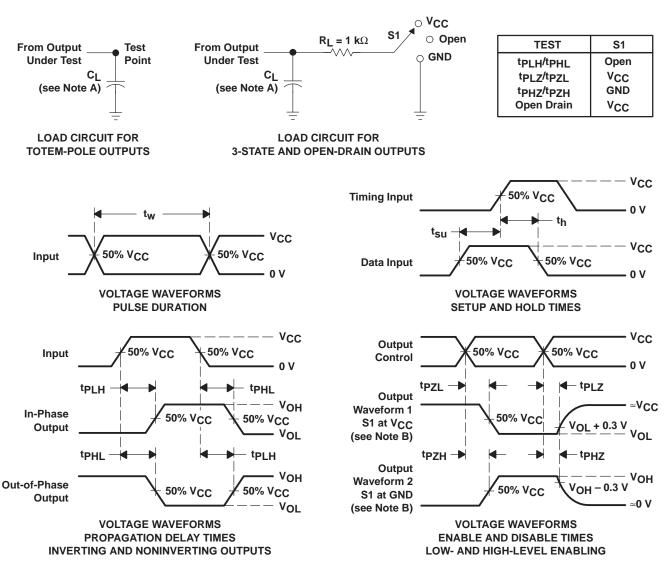
switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	OUTPUT CAPACITANCE	T _A = 25°C	MIN MAX	UNIT		
PARAMETER				MIN TYP MAX	IVIIN IVIAA	ONIT		
t _{PLH}	A or B	Y	C: 15 pF					
^t PHL	AUIB			Α ΟΙ Β	C _L = 15 pF	CL = 13 μr		
^t PLH	A or B	V	C: _ 50 pF					
tPHL	AUIB	ĭ	C _L = 50 pF			ns		

operating characteristics, V_{CC} = 5 V, T_A = 25°C

PARAMETER		TEST CONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance	No load, f = 1 MHz		pF

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \ \Omega$, $t_f \leq 3 \ ns$.
- D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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